

SN65LVDS33, SN65LVDT33 SN65LVDS34, SN65LVDT34

SLLS490B-MARCH 2001-REVISED NOVEMBER 2004

www.ti.com

HIGH-SPEED DIFFERENTIAL RECEIVERS

Check for Samples: SN65LVDS33, SN65LVDT33, SN65LVDS34, SN65LVDT34

FEATURES

- 400-Mbps Signaling Rate⁽¹⁾ and 200-Mxfr/s Data Transfer Rate
- Operates With a Single 3.3-V Supply
- -4 V to 5 V Common-Mode Input Voltage Range
- Differential Input Thresholds <±50 mV With 50 mV of Hysteresis Over Entire Common-Mode Input Voltage Range
- Integrated 110-Ω Line Termination Resistors On LVDT Products
- TSSOP Packaging (33 Only)
- Complies With TIA/EIA-644 (LVDS)
- Active Failsafe Assures a High-Level Output With No Input
- Bus-Pin ESD Protection Exceeds 15 kV HBM
- Input Remains High-Impedance on Power Down
- TTL Inputs Are 5 V Tolerant
- Pin-Compatible With the AM26LS32, SN65LVDS32B, µA9637, SN65LVDS9637B
- ⁽¹⁾ The signalling rate of a line, is the number of voltage transitions that are made per second expressed in the units bps (bits per second).

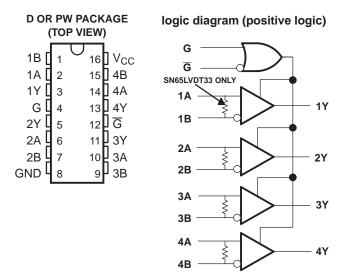
DESCRIPTION

This family of four LVDS data line receivers offers the widest common-mode input voltage range in the industry. These receivers provide an input voltage range specification compatible with a 5-V PECL signal as well as an overall increased ground-noise tolerance. They are in industry standard footprints with integrated termination as an option.

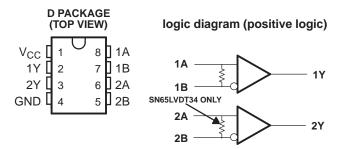
Precise control of the differential input voltage thresholds allows for inclusion of 50 mV of input voltage hysteresis to improve noise rejection on slowly changing input signals. The input thresholds are still no more than ±50 mV over the full input common-mode voltage range.

The high-speed switching of LVDS signals usually necessitates the use of a line impedance matching resistor at the receiving-end of the cable or transmission media. The SN65LVDT series of receivers eliminates this external resistor by integrating it with the receiver. The nonterminated SN65LVDS series is also available for multidrop or other termination circuits.

SN65LVDS33D, SN65LVDT33D SN65LVDS33PW, SN65LVDT33PW



SN65LVDS34D, SN65LVDT34D





Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

SN65LVDS33, SN65LVDT33 SN65LVDS34, SN65LVDT34

SLLS490B-MARCH 2001-REVISED NOVEMBER 2004



www.ti.com



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

| PART NUMBER ⁽²⁾ | NUMBER OF RECEIVERS | TERMINATION RESISTOR | SYMBOLIZATION |
|-------------------------------|------------------------|-------------------------|---------------|
| SN65LVDS33D | 4 | No | LVDS33 |
| SN65LVDS33PW | 4 | No | LVDS33 |
| SN65LVDTS33D | 4 | Yes | LVDT33 |
| SN65LVDT33PW | 4 | Yes | LVDT33 |
| SN65LVDS34D | 2 | No | LVDS34 |
| SN65LVDT34D | 2 | Yes | LVDT34 |

For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI

website at www.ti.com.

(2) Add the suffix R for taped and reeled carrier.

DESCRIPTION (CONTINUED)

The receivers can withstand ±15 kV human-body model (HBM) and ±600 V machine model (MM) electrostatic discharges to the receiver input pins with respect to ground without damage. This provides reliability in cabled and other connections where potentially damaging noise is always a threat.

The receivers also include a (patent pending) failsafe circuit that will provide a high-level output within 600 ns after loss of the input signal. The most common causes of signal loss are disconnected cables, shorted lines, or powered-down transmitters. The failsafe circuit prevents noise from being received as valid data under these fault conditions. This feature may also be used for Wired-Or bus signaling. See *The Active Failsafe Feature of the SN65LVDS32B* application note.

The intended application and signaling technique of these devices is point-to-point baseband data transmission over controlled impedance media of approximately 100 Ω . The transmission media may be printed-circuit board traces, backplanes, or cables. The ultimate rate and distance of data transfer is dependent upon the attenuation characteristics of the media and the noise coupling to the environment.

The SN65LVDS33, SN65LVDT33, SN65LVDS34 and SN65LVDT34 are characterized for operation from -40°C to 85°C.

| SN65LVDS33 and | SN65L | | | SN65LVDS34 and SN65LVDT34 | | | |
|------------------------------------|-------|------|--------|------------------------------------|--------|--|--|
| DIFFERENTIAL INPUT | | BLES | OUTPUT | DIFFERENTIAL INPUT | OUTPUT | | |
| $V_{ID} = V_A - V_B$ | G | G | Y | $V_{ID} = V_A - V_B$ | Y | | |
| | Н | Х | Н | V _{ID} ≥ −32 mV | Н | | |
| V _{ID} ≥ –32 mV | Х | L | н | –100 mV < V _{ID} ≤ –32 mV | ? | | |
| 100 m/(-1)/(22 m)/(-1) | Н | Х | ? | V _{ID} ≤ −100 mV | L | | |
| –100 mV < V _{ID} ≤ –32 mV | Х | L | ? | Open | н | | |
| | Н | Х | L | | | | |
| V _{ID} ≤ −100 mV | Х | L | L | | | | |
| Х | L | Н | Z | | | | |
| 0 | Н | Х | Н | | | | |
| Open | Х | L | н | | | | |

 Table 1. Function Tables⁽¹⁾

(1) H = high level, L = low level, X = irrelevant, Z = high impedance (off), ? = indeterminate

2

Copyright © 2001–2004, Texas Instruments Incorporated

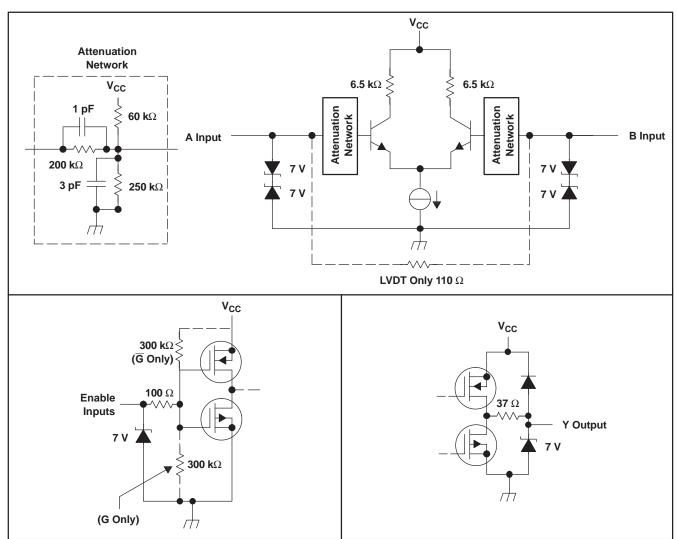


SN65LVDS33, SN65LVDT33 SN65LVDS34, SN65LVDT34

3

SLLS490B-MARCH 2001-REVISED NOVEMBER 2004

EQUIVALENT INPUT AND OUTPUT SCHEMATIC DIAGRAMS



Copyright © 2001–2004, Texas Instruments Incorporated Submit Documentation Feedback
Product Folder Link(s): SN65LVDS33_SN65LVDT33_SN65LVDS34_SN65LVDT34

SN65LVDS33, SN65LVDT33 SN65LVDS34, SN65LVDT34

SLLS490B-MARCH 2001-REVISED NOVEMBER 2004



www.ti.com

ABSOLUTE MAXIMUM RATINGS

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

| | | UNIT |
|---------------------------------------|------------------------------|------------------------------|
| Supply voltage range, V _{CC} | 2 (2) | –0.5 V to 4 V |
| | Enables or Y | -1 V to 6 V |
| Voltage range | A or B | –5 V to 6 V |
| | $ V_A - V_B $ (LVDT) | 1 V |
| Electrostatic discharge | A, B, and GND ⁽³⁾ | Class 3, A: 15 kV, B: 500 V |
| Charged-device mode | All pins ⁽⁴⁾ | ±500 V |
| Continuous power dissipation | | See Dissipation Rating Table |
| Storage temperature rang | torage temperature range | |

(1) Stresses beyond those listed under *absolute maximum ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *recommended operating conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) All voltage values, except differential I/O bus voltages, are with respect to network ground terminal.

(3) Tested in accordance with JEDEC Standard 22, Test Method A114-A.

(4) Tested in accordance with JEDEC Standard 22, Test Method C101.

DISSIPATION RATING TABLE

| PACKAGE | T _A ≤ 25°C POWER RATING | OPERATING FACTOR ⁽¹⁾ ABOVE $T_A = 25^{\circ}C$ | T _A = 85°C POWER RATING |
|---------|---------------------------------------|--|---------------------------------------|
| D8 | 725 mW | 5.8 mW/°C | 377 mW |
| PW16 | 774 mW | 6.2 mW/°C | 402 mW |
| D16 | 950 mW | 7.6 mW/°C | 494 mW |

(1) This is the inverse of the junction-to-ambient thermal resistance when board-mounted and with no air flow.

RECOMMENDED OPERATING CONDITIONS

| | | | MIN | NOM | MAX | UNIT |
|-------------------|--|-------------------------------|-----|-----|-----|------|
| V _{CC} | Supply voltage | | 3 | 3.3 | 3.6 | V |
| V _{IH} | High-level input voltage | Enables | 2 | | 5 | V |
| V _{IL} | Low-level input voltage | Enables | 0 | | 0.8 | V |
| | High-level input voltage Enables Low-level input voltage Enables ID Magnitude of differential input voltage LVDS LVDT | LVDS | 0.1 | | 3 | |
| V _{ID} | | LVDT | | | 0.8 | v |
| V_I or V_{IC} | Voltage at any bus terminal (separately o | r common-mode) | -4 | | 5 | V |
| T _A | Operating free-air temperature | perating free-air temperature | | | | °C |

4



ELECTRICAL CHARACTERISTICS

over recommended operating conditions (unless otherwise noted)

| | PARAMETER | | TEST CONDITIONS | MIN | TYP ⁽¹⁾ | MAX | UNIT | | |
|--|---|--------------|---|-----------------|--------------------|-----------|------------------|--|--|
| V _{IT1} V _{IT2} | Positive-going differential inp Negative-going differential in | 5 | V _{IB} = -4 V or 5 V, See Figure 1 and Figure 2 | -50 | | 50 | mV | | |
| | threshold Differential input failsafe volta | an threshold | See Table 2 and Figure 5 | -32 | | -100 | mV | | |
| V _{IT3} V _{ID(HYS)} | Differential input voltage hyst $V_{IT1} - V_{IT2}$ | • | | -32 | 50 | -100 | mV | | |
| V _{OH} | High-level output voltage | | $I_{OH} = -4 \text{ mA}$ | 2.4 | | | V | | |
| V _{OL} | Low-level output voltage | | I _{OL} = 4 mA | | | 0.4 | V | | |
| | | | G at V _{CC} , No load, Steady-state | | 16 | 23 | | | |
| I _{CC} | Supply current SN65LVDx33 | | G at GND | | 1.1 | 5 | mA | | |
| | | SN65LVDx34 | No load, Steady-state | | 8 | 12 | | | |
| | | | V _I = 0 V, Other input open | | | ±20 | | | |
| | Input current | SN65LVDS | $V_I = 2.4 V$, Other input open | | | ±20 μA | | | |
| | | 31032703 | $V_I = -4 V$, Other input open | | | ±75 | ′5 ^{μΑ} | | |
| | | | $V_I = 5 V$, Other input open | | | ±40 | <u> </u> | | |
| lı | (A or B inputs) | | $V_I = 0 V$, Other input open | | | ±40 | | | |
| | | SN65LVDT | V _I = 2.4 V, Other input open | er input open ± | | | | | |
| | | SNOSLVDT | $V_I = -4 V$, Other input open | | | ±150 | ±150 µA | | |
| | | | $V_I = 5 V$, Other input open | | | ±80 | | | |
| I _{ID} | Differential input current | SN65LVDS | V_{ID} = 100 mV, V_{IC} = -4 V or 5 V | | | ±3 | μA | | |
| U | $(I_{IA} - I_{IB})$ | SN65LVDT | V_{ID} = 200 mV, V_{IC} = –4 V or 5 V | 1.55 | | 2.22 | mA | | |
| | | SN65LVDS | V_A or V_B = 0 V or 2.4 V, V_{CC} = 0 V | | | ±20 | | | |
| I | Power-off input current | 514032703 | V_A or $V_B = -4$ or 5 V, $V_{CC} = 0$ V | | | ±50 | μA | | |
| I _{I(OFF)} | (A or B inputs) | SN65LVDT | V_A or V_B = 0 V or 2.4 V, V_{CC} = 0 V | | | ±30 | μΛ | | |
| | | SNOSEVET | V_A or V_B = –4 V or 5 V, V_{CC} = 0 V | | | ±100 | | | |
| I _{IH} | High-level input current (enal | oles) | V _{IH} = 2 V | | | 10 | μA | | |
| IIL | Low-level input current (enab | oles) | V _{IL} = 0.8 V | | | 10 | μA | | |
| l _{oz} | High-impedance output curre | ent | | -10 | | 10 | μA | | |
| Cl | Input capacitance, A or B inp | ut to GND | $V_{I} = 0.4 \sin (4E6\pi t) + 0.5 V$ | | 5 | | pF | | |

(1) All typical values are at 25° C and with a 3.3 V supply.

SN65LVDS33, SN65LVDT33 SN65LVDS34, SN65LVDT34

SLLS490B-MARCH 2001-REVISED NOVEMBER 2004



www.ti.com

SWITCHING CHARACTERISTICS

over recommended operating conditions (unless otherwise noted)

| | PARAMETER | TEST CONDITIONS | MIN | TYP ⁽¹⁾ | MAX | UNIT |
|---------------------|--|--------------------------------------|-----|--------------------|-----|------|
| t _{PLH(1)} | Propagation delay time, low-to-high-level output | | 2.5 | 4 | 6 | ns |
| t _{PHL(1)} | Propagation delay time, high-to-low-level output | See Figure 3 | 2.5 | 4 | 6 | ns |
| t _{d1} | Delay time, failsafe deactivate time | $C_1 = 10 \text{ pF}$, See Figure 3 | | | 9 | ns |
| t _{d2} | Delay time, failsafe activate time | and Figure 6 | 0.3 | | 1.5 | μs |
| t _{sk(p)} | Pulse skew (t _{PHL(1)} - t _{PLH(1)}) | | | 200 | | ps |
| t _{sk(o)} | Output skew ⁽²⁾ | | | 150 | | ps |
| t _{sk(pp)} | Part-to-part skew ⁽³⁾ | See Figure 3 | | | 1 | ns |
| t _r | Output signal rise time | | | 0.8 | | ns |
| t _f | Output signal fall time | | | 0.8 | | ns |
| t _{PHZ} | Propagation delay time, high-level-to-high-impedance output | | | 5.5 | 9 | ns |
| t _{PLZ} | Propagation delay time, low-level-to-high-impedance output | | | 4.4 | 9 | ns |
| t _{PZH} | Propagation delay time, high-impedance -to-high-level output | See Figure 4 | | 3.8 | 9 | ns |
| t _{PZL} | Propagation delay time, high-impedance-to-low-level output | | | 7 | 9 | ns |

(1) All typical values are at 25°C and with a 3.3-V supply.

(2) $t_{sk(0)}$ is the magnitude of the time difference between the t_{PLH} or t_{PHL} of all receivers of a single device with all of their inputs driven together.

(3) t_{sk(pp)} is the magnitude of the time difference in propagation delay times between any specified terminals of two devices when both devices operate with the same supply voltages, at the same temperature, and have identical packages and test circuits.

PARAMETER MEASUREMENT INFORMATION

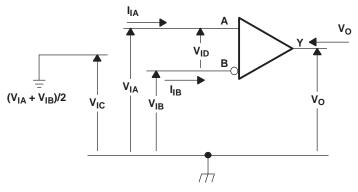
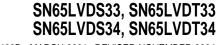


Figure 1. Voltage and Current Definitions

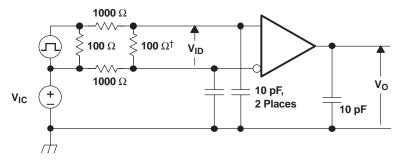


SLLS490B-MARCH 2001-REVISED NOVEMBER 2004

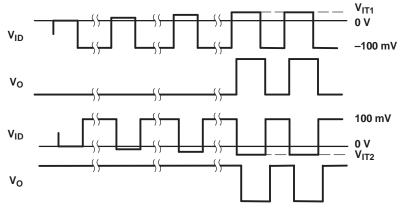


www.ti.com

PARAMETER MEASUREMENT INFORMATION (continued)



[†] Remove for testing LVDT device.



NOTE: Input signal of 3 Mpps, duration of 167 ns, and transition time of <1 ns.

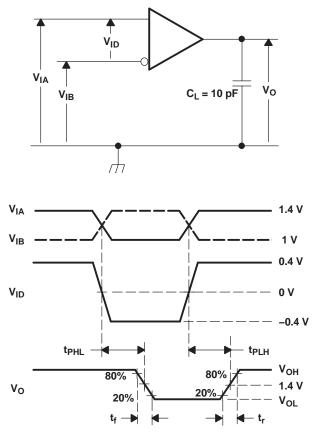
Figure 2. V_{IT1} and V_{IT2} Input Voltage Threshold Test Circuit and Definitions

8



www.ti.com



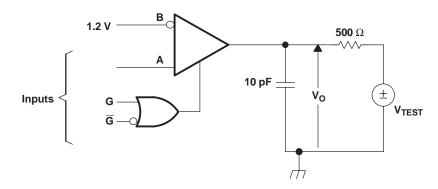


A. All input pulses are supplied by a generator having the following characteristics: t_r or t_f ≤ 1 ns, pulse repetition rate (PRR) = 50 Mpps, pulsewidth = 10 ±0.2 ns. C_L includes instrumentation and fixture capacitance within 0,06 mm of the D.U.T.





PARAMETER MEASUREMENT INFORMATION (continued)



NOTE: All input pulses are supplied by a generator having the following characteristics: t_r or $t_f \leq 1$ ns, pulse repetition rate (PRR) = 0.5 Mpps, pulsewidth = 500 ±10 ns . C_L includes instrumentation and fixture capacitance within 0,06 mm of the D.U.T.

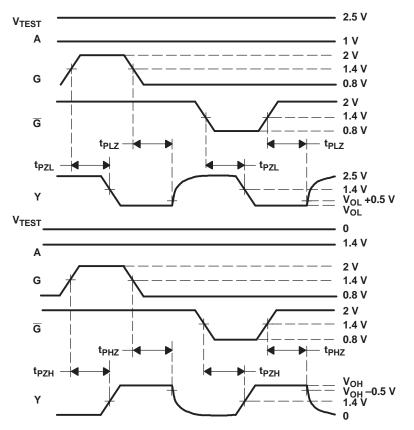


Figure 4. Enable/Disable Time Test Circuit and Waveforms

SN65LVDS33, SN65LVDT33 SN65LVDS34, SN65LVDT34 SLLS490B – MARCH 2001 – REVISED NOVEMBER 2004

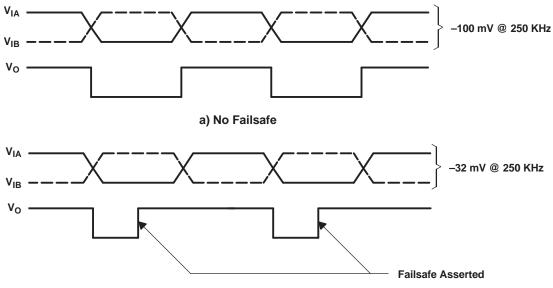


www.ti.com

Table 2. Receiver Minimum and Maximum VIT3Input Threshold Test Voltages

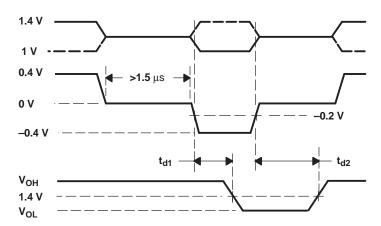
| APPLIED V | OLTAGES ⁽¹⁾ | RESULTANT INPUTS | | | | | | |
|----------------------|---|------------------|----------------------|--------|--|--|--|--|
| V _{IA} (mV) | V _{IA} (mV) V _{IB} (mV) | | V _{IC} (mV) | Output | | | | |
| -4000 | -3900 | -100 | -3950 | L | | | | |
| -4000 | -3968 | -32 | -3984 | н | | | | |
| 4900 | 5000 | -100 | 4950 | L | | | | |
| 4968 | 5000 | -32 | 4984 | н | | | | |

(1) These voltages are applied for a minimum of $1.5 \,\mu s$.



b) Failsafe Asserted



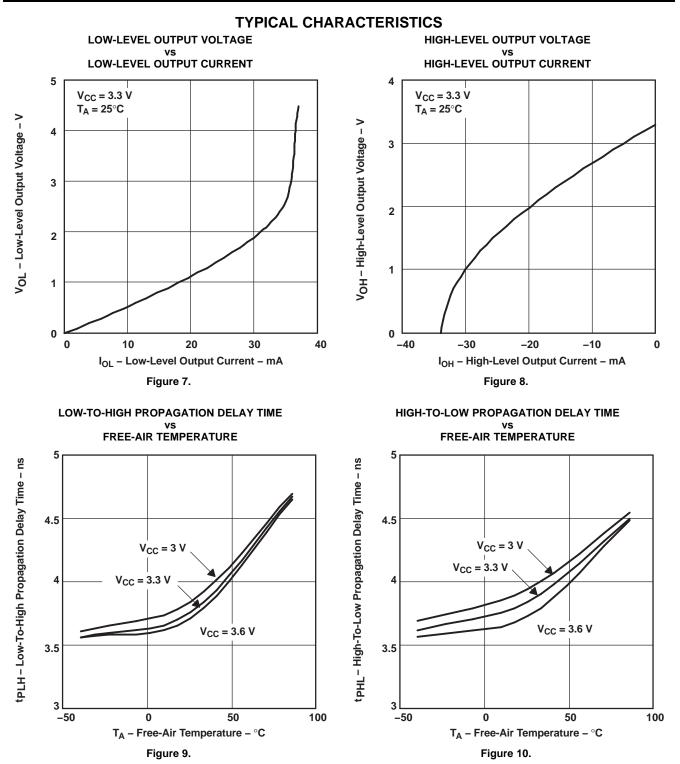






SN65LVDS33, SN65LVDT33 SN65LVDS34, SN65LVDT34

SLLS490B-MARCH 2001-REVISED NOVEMBER 2004

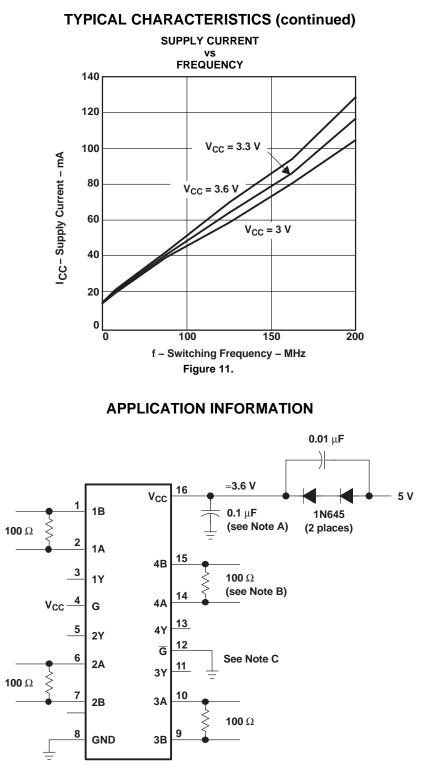


SN65LVDS34, SN65LVDT34 SLLS490B – MARCH 2001 – REVISED NOVEMBER 2004

SN65LVDS33, SN65LVDT33



www.ti.com



- A. Place a 0.1-µF Z5U ceramic, mica or polystyrene dielectric, 0805 size, chip capacitor between V_{CC} and the ground plane. The capacitor should be located as close as possible to the device terminals.
- B. The termination resistance value should match the nominal characteristic impedance of the transmission media with $\pm 10\%$.
- C. Unused enable inputs should be tied to $V_{\mbox{\scriptsize CC}}$ or GND as appropriate.

Figure 12. Operation With 5-V Supply

Copyright © 2001–2004, Texas Instruments Incorporated



RELATED INFORMATION

IBIS modeling is available for this device. Contact the local TI sales office or the TI Web site at *www.ti.com* for more information.

For more application guidelines, see the following documents:

- Low-Voltage Differential Signalling Design Notes (SLLA014)
- Interface Circuits for TIA/EIA-644 (LVDS) (SLLA038)
- Reducing EMI With LVDS (SLLA030)
- Slew Rate Control of LVDS Circuits (SLLA034)
- Using an LVDS Receiver With RS-422 Data (SLLA031)
- Evaluating the LVDS EVM (SLLA033)

ACTIVE FAILSAFE FEATURE

A differential line receiver commonly has a failsafe circuit to prevent it from switching on input noise. Current LVDS failsafe solutions require either external components with subsequent reductions in signal quality or integrated solutions with limited application. This family of receivers has a new integrated failsafe that solves the limitations seen in present solutions. A detailed theory of operation is presented in application note *The Active Failsafe Feature of the SN65LVDS32B*, (SLLA082A).

The following figure shows one receiver channel with active failsafe. It consists of a main receiver that can respond to a high-speed input differential signal. Also connected to the input pair are two failsafe receivers that form a window comparator. The window comparator has a much slower response than the main receiver and it detects when the input differential falls below 80 mV. A 600-ns failsafe timer filters the window comparator outputs. When failsafe is asserted, the failsafe logic drives the main receiver output to logic high.

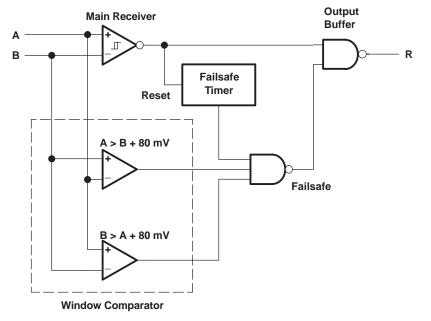


Figure 13. Receiver With Active Failsafe

ECL/PECL-TO-LVTTL CONVERSION WITH TI'S LVDS RECEIVER

The various versions of emitter-coupled logic (i.e., ECL, PECL and LVPECL) are often the physical layer of choice for system designers. Designers know of the established technology and that it is capable of high-speed data transmission. In the past, system requirements often forced the selection of ECL. Now technologies like

Copyright © 2001–2004, Texas Instruments Incorporated

SN65LVDS33, SN65LVDT33

SN65LVDS34. SN65LVDT34

SLLS490B-MARCH 2001-REVISED NOVEMBER 2004

SN65LVDS33, SN65LVDT33 SN65LVDS34, SN65LVDT34



www.ti.com

SLLS490B-MARCH 2001-REVISED NOVEMBER 2004

LVDS provide designers with another alternative. While the total exchange of ECL for LVDS may not be a design option, designers have been able to take advantage of LVDS by implementing a small resistor divider network at the input of the LVDS receiver. TI has taken the next step by introducing a wide common-mode LVDS receiver (no divider network required) which can be connected directly to an ECL driver with only the termination bias voltage required for ECL termination (V_{CC} -2 V).

Figure 14 and Figure 15 show the use of an LV/PECL driver driving 5 meters of CAT-5 cable and being received by TI's wide common-mode receiver and the resulting eye-pattern. The values for R3 are required in order to provide a resistor path to ground for the LV/PECL driver. With no resistor divider, R1 simply needs to match the characteristic load impedance of 50 Ω . The R2 resistor is a small value and is intended to minimize any possible common-mode current reflections.

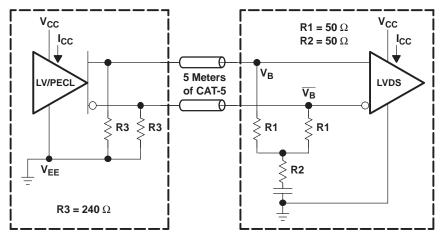


Figure 14. LVPECL or PECL to Remote Wide Common-Mode LVDS Receiver

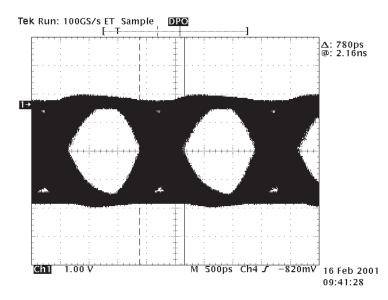


Figure 15. LV/PECL to Remote SN65LVDS33 at 500 Mbps Receiver Output (CH1)

TEST CONDITIONS

- V_{CC} = 3.3 V
- T_A = 25°C (ambient temperature)
- All four channels switching simultaneously with NRZ data. Scope is pulse-triggered simultaneously with NRZ data.



EQUIPMENT

- Tektronix PS25216 programmable power supply
- Tektronix HFS 9003 stimulus system
- Tektronix TDS 784D 4-channel digital phosphor oscilloscope DPO

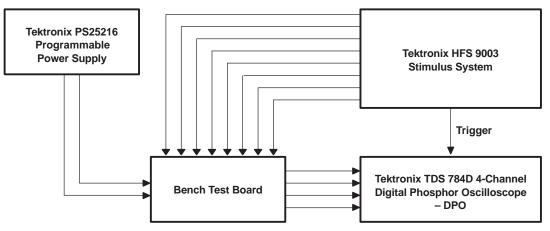


Figure 16. Equipment Setup

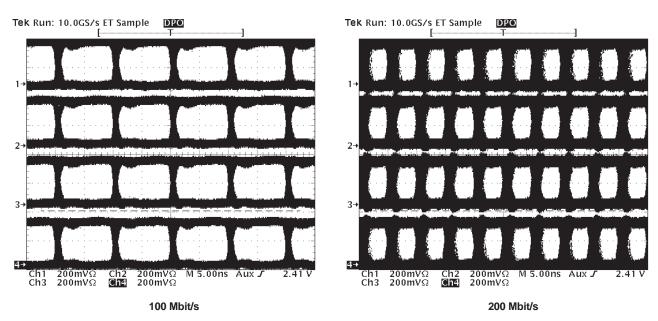


Figure 17. Typical Eye Pattern SN65LVDS33



10-Dec-2020

PACKAGING INFORMATION

| Orderable Device | Status (1) | Package Type | Package Drawing | Pins | Package Qty | Eco Plan (2) | Lead finish/ Ball material (6) | MSL Peak Temp (3) | Op Temp (°C) | Device Marking (4/5) | Samples |
|------------------|---------------|--------------|--------------------|------|----------------|-----------------|--------------------------------------|----------------------|--------------|-------------------------|---------|
| SN65LVDS33D | ACTIVE | SOIC | D | 16 | 40 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | LVDS33 | Samples |
| SN65LVDS33DG4 | ACTIVE | SOIC | D | 16 | 40 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | LVDS33 | Samples |
| SN65LVDS33DR | ACTIVE | SOIC | D | 16 | 2500 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | LVDS33 | Samples |
| SN65LVDS33DRG4 | ACTIVE | SOIC | D | 16 | 2500 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | LVDS33 | Samples |
| SN65LVDS33PW | ACTIVE | TSSOP | PW | 16 | 90 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | LVDS33 | Samples |
| SN65LVDS33PWR | ACTIVE | TSSOP | PW | 16 | 2000 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | LVDS33 | Samples |
| SN65LVDS34D | ACTIVE | SOIC | D | 8 | 75 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | LVDS34 | Samples |
| SN65LVDS34DR | ACTIVE | SOIC | D | 8 | 2500 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | LVDS34 | Samples |
| SN65LVDS34DRG4 | ACTIVE | SOIC | D | 8 | 2500 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | LVDS34 | Samples |
| SN65LVDT33D | ACTIVE | SOIC | D | 16 | 40 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | LVDT33 | Samples |
| SN65LVDT33DG4 | ACTIVE | SOIC | D | 16 | 40 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | LVDT33 | Samples |
| SN65LVDT33PW | ACTIVE | TSSOP | PW | 16 | 90 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | LVDT33 | Samples |
| SN65LVDT33PWG4 | ACTIVE | TSSOP | PW | 16 | 90 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | LVDT33 | Samples |
| SN65LVDT33PWR | ACTIVE | TSSOP | PW | 16 | 2000 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | LVDT33 | Samples |
| SN65LVDT34D | ACTIVE | SOIC | D | 8 | 75 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | LVDT34 | Samples |
| SN65LVDT34DG4 | ACTIVE | SOIC | D | 8 | 75 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | LVDT34 | Samples |
| SN65LVDT34DR | ACTIVE | SOIC | D | 8 | 2500 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | LVDT34 | Samples |

⁽¹⁾ The marketing status values are defined as follows: **ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design. **PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.



10-Dec-2020

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF SN65LVDS33 :

Enhanced Product: SN65LVDS33-EP

NOTE: Qualified Version Definitions:

• Enhanced Product - Supports Defense, Aerospace and Medical Applications

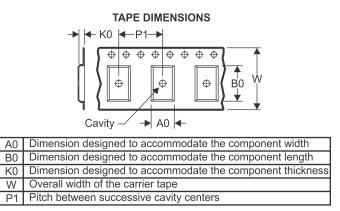
PACKAGE MATERIALS INFORMATION

Texas Instruments

www.ti.com

TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

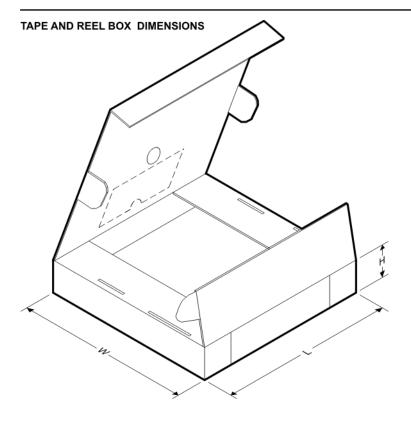


| Device | Package Type | Package Drawing | | SPQ | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|---------------|-----------------|--------------------|----|------|--------------------------|--------------------------|------------|------------|------------|------------|-----------|------------------|
| SN65LVDS33DR | SOIC | D | 16 | 2500 | 330.0 | 16.4 | 6.5 | 10.3 | 2.1 | 8.0 | 16.0 | Q1 |
| SN65LVDS33PWR | TSSOP | PW | 16 | 2000 | 330.0 | 12.4 | 6.9 | 5.6 | 1.6 | 8.0 | 12.0 | Q1 |
| SN65LVDS34DR | SOIC | D | 8 | 2500 | 330.0 | 12.4 | 6.4 | 5.2 | 2.1 | 8.0 | 12.0 | Q1 |
| SN65LVDT33PWR | TSSOP | PW | 16 | 2000 | 330.0 | 12.4 | 6.9 | 5.6 | 1.6 | 8.0 | 12.0 | Q1 |
| SN65LVDT34DR | SOIC | D | 8 | 2500 | 330.0 | 12.4 | 6.4 | 5.2 | 2.1 | 8.0 | 12.0 | Q1 |



PACKAGE MATERIALS INFORMATION

5-Jan-2022

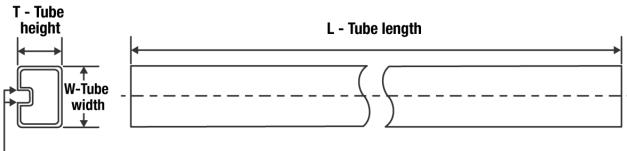


*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
|---------------|--------------|-----------------|------|------|-------------|------------|-------------|
| SN65LVDS33DR | SOIC | D | 16 | 2500 | 340.5 | 336.1 | 32.0 |
| SN65LVDS33PWR | TSSOP | PW | 16 | 2000 | 350.0 | 350.0 | 43.0 |
| SN65LVDS34DR | SOIC | D | 8 | 2500 | 340.5 | 336.1 | 25.0 |
| SN65LVDT33PWR | TSSOP | PW | 16 | 2000 | 350.0 | 350.0 | 43.0 |
| SN65LVDT34DR | SOIC | D | 8 | 2500 | 340.5 | 336.1 | 25.0 |



TUBE



B - Alignment groove width

| All dimensions are nominal | | | | | | | | |
|----------------------------|--------------|--------------|------|-----|--------|--------|--------|--------|
| Device | Package Name | Package Type | Pins | SPQ | L (mm) | W (mm) | Τ (μm) | B (mm) |
| SN65LVDS33D | D | SOIC | 16 | 40 | 507 | 8 | 3940 | 4.32 |
| SN65LVDS33DG4 | D | SOIC | 16 | 40 | 507 | 8 | 3940 | 4.32 |
| SN65LVDS33PW | PW | TSSOP | 16 | 90 | 530 | 10.2 | 3600 | 3.5 |
| SN65LVDS34D | D | SOIC | 8 | 75 | 507 | 8 | 3940 | 4.32 |
| SN65LVDS34D | D | SOIC | 8 | 75 | 505.46 | 6.76 | 3810 | 4 |
| SN65LVDT33D | D | SOIC | 16 | 40 | 505.46 | 6.76 | 3810 | 4 |
| SN65LVDT33DG4 | D | SOIC | 16 | 40 | 505.46 | 6.76 | 3810 | 4 |
| SN65LVDT33PW | PW | TSSOP | 16 | 90 | 530 | 10.2 | 3600 | 3.5 |
| SN65LVDT33PWG4 | PW | TSSOP | 16 | 90 | 530 | 10.2 | 3600 | 3.5 |
| SN65LVDT34D | D | SOIC | 8 | 75 | 507 | 8 | 3940 | 4.32 |
| SN65LVDT34D | D | SOIC | 8 | 75 | 505.46 | 6.76 | 3810 | 4 |
| SN65LVDT34DG4 | D | SOIC | 8 | 75 | 505.46 | 6.76 | 3810 | 4 |
| SN65LVDT34DG4 | D | SOIC | 8 | 75 | 507 | 8 | 3940 | 4.32 |

D (R-PDSO-G16)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AC.



4211283-4/E 08/12

D (R-PDSO-G16) PLASTIC SMALL OUTLINE Stencil Openings (Note D) Example Board Layout (Note C) –16x0,55 -14x1,27 -14x1,27 16x1,50 5,40 5.40 Example Non Soldermask Defined Pad Example Pad Geometry (See Note C) 0,60 .55 Example 1. Solder Mask Opening (See Note E) -0,07 All Around

NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
 E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



PW0016A



PACKAGE OUTLINE

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.



PW0016A

EXAMPLE BOARD LAYOUT

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



PW0016A

EXAMPLE STENCIL DESIGN

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

9. Board assembly site may have different recommendations for stencil design.



^{8.} Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

D0008A



PACKAGE OUTLINE

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



NOTES:

1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.

- 2. This drawing is subject to change without notice.
- 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
- 4. This dimension does not include interlead flash.
- 5. Reference JEDEC registration MS-012, variation AA.



D0008A

EXAMPLE BOARD LAYOUT

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



D0008A

EXAMPLE STENCIL DESIGN

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

9. Board assembly site may have different recommendations for stencil design.



IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATA SHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, regulatory or other requirements.

These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you will fully indemnify TI and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to TI's Terms of Sale or other applicable terms available either on ti.com or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products.

TI objects to and rejects any additional or different terms you may have proposed.

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2022, Texas Instruments Incorporated

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for LVDS Interface IC category:

Click to view products by Texas Instruments manufacturer:

Other Similar products are found below :

SN65LV1212DBR RS90LV011YF5 MS90C104 MS90C031 MAX9176EUB+T SN65LVP16DRFT MAX9180EXT+T BU90LV048-E2 DS90LV047ATMX/NOPB DS90LT012AQMFX/NOPB SN65LVDS051PWRQ1 SN55LVDS31W DS90C387VJDXNOPB SN65DSI84TPAPRQ1 ADN4696EBRZ ADN4696EBRZ-RL7 ADN4693EBRZ ADN4670BCPZ MAX9112ESA+T THC63LVD827-2BRA BU90T82-ZE2 PTN3460IBSF1MP DS90LV011ATMFX/NOPB SN65LVDS2DBVTG4 HT651023BRSZ HT651224BRSZ MAX9122EUE+T MAX9123EUE+T MAX9174EUB+T BU90LV049A-E2 MAX9110EKA+T MAX9130EXTT NBA3N012CSNT1G NBA3N011SSNT1G MS1224 MS9218 NB3L8504SDTR2G FIN1001M5X FIN1017MX FIN1027AMX FIN1215MTDX FIN1217MTDX NB3L8504SDTG PTN3460IBS/F2MP NB3N4666CDTR2G MAX9121EUE+ BU90LV047A-E2 BU8255KVT-E2 SN65CML100DR SN65LVDM051DR